

1.5V Drive Pch MOSFET

RQ1A070ZP

Structure

Silicon P-channel MOSFET

● Features

- 1) Low On-resistance.
- 2) Low voltage drive. (1.5 V)
- 3) High power package.

Applications

Switching

Packaging specifications

	Package	Taping				
Type	Code	TR				
	Basic ordering unit (pieces)	3000				
RQ1A070ZI	0					

●Absolute maximum ratings (Ta=25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter		Symbol		Limits	Unit
Drain-source voltage		V _{DSS}		-12	V
Gate-source voltage	V _{GSS}		±10	V	
Drain current	Continuous	I_D		±7	Α
Diam current	Pulsed	I_{DP}	*1	±28	А
Source current	Continuous	Is		-1	А
(Body diode)	Pulsed	I _{SP}	*1	-28	А
Total power dissipation	PD	*2	1.5	W	
Channel temperature	Tch		150	°C	
Range of Storage temperature		Tstg		-55 to +150	°C

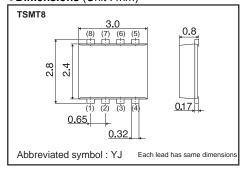
^{*1} Pw≤10μs, Duty cycle≤1% *2 When mounted on a ceramic board

●Thermal resistance

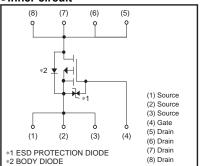
Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	83.3	°C/W

^{*} Mounted on a ceramic board.

●Dimensions (Unit:mm)



●Inner circuit



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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	_	_	±10	μΑ	V _{GS} =±10V, V _{DS} =0V
Drain-source breakdown voltage	V(BR) DSS	-12	_	_	V	ID=-1mA, VGS=0V
Zero gate voltage drain current	IDSS	_	_	-1	μΑ	V _{DS} = -12V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-0.3	-	-1.0	V	V _{DS} = -6V, I _D = -1mA
Static drain-source on-state resistance		_	8	12	mΩ	I _D = -7A, V _G S= -4.5V
	RDS (on)*	-	11	16	mΩ	I _D = -3.5A, V _G S= -2.5V
	IXDS (on)	-	15	23	mΩ	I _D = -3.5A, V _{GS} = -1.8V
		-	19	38	mΩ	ID= -1.4A, VGS= -1.5V
Forward transfer admittance	Y _{fs} *	12	-	-	S	V _{DS} = -6V, I _D = -7A
Input capacitance	Ciss	_	7400	_	pF	V _{DS} = -6V
Output capacitance	Coss	_	800	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	750	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	-	35	_	ns	Vpp≒-6V
Rise time	tr *	-	95	-	ns	ID= -3.5A
Turn-off delay time	td (off) *	-	310	_	ns	V _{GS} = −4.5V R _L ≒1.7Ω
Fall time	t _f *	-	190	-	ns	R _G =10Ω
Total gate charge	Qg *	_	58	_	nC	V _{DD} ≒-6V
Gate-source charge	Q _{gs} *	_	11	-	nC	I _D =-7A V _G s=-4.5V
Gate-drain charge	Q _{gd} *	_	10	-	nC	RL=0.86Ω / R _G =10Ω

^{*}Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

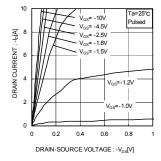
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	-1.2	V	I _S = -7A, V _{GS} =0V

^{*} Pulsed

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RQ1A070ZP Data Sheet

Electrical characteristics curves





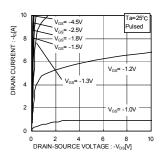


Fig.2 Typical output characteristics(II)

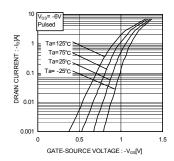
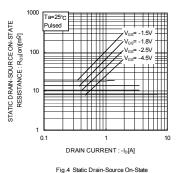


Fig.3 Typical Transfer Characteristics



Resistance vs. Drain Current(I)

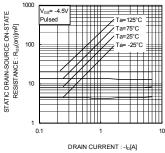


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II

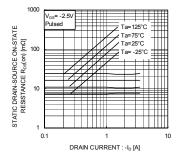


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(Ⅲ)

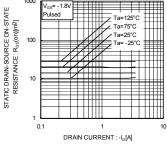


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

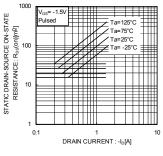


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(IV)

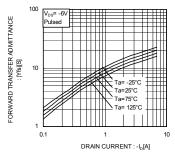
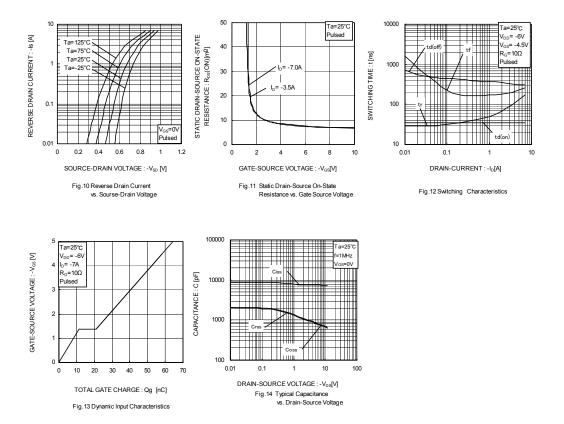


Fig.9 Forward Transfer Admittance vs. Drain Current



Measurement circuits

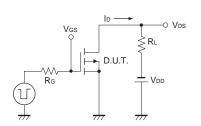


Fig.1-1 Switching Time Measurement Circuit

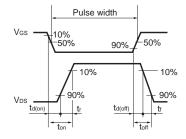


Fig.1-2 Switching Waveforms

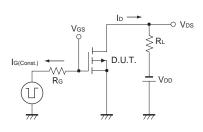


Fig.2-1 Gate Charge Measurement Circuit

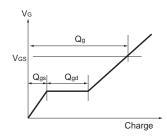


Fig.2-2 Gate Charge Waveform

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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